

www.ti.com .. SBOS339B–OCTOBER 2005–REVISED MAY 2008

High-Speed, Closed-Loop Buffer

- **2**•
-
- • **Flexible Supply Range: ±1.4V to ±6.3V Dual Supplies +2.8V to +12.6V Single Supply**
- •
- •
- •
- **Standard Buffer Pinout**
- •**Optional Mid-Supply Reference Buffer**

APPLICATIONS

- •**Low Impedance Reference Buffers**
- **Clock Distribution Circuits**
- •**Video/Broadcast Equipment**
- •**Communications Equipment**
- •**High-Speed Data Acquisition**
- •**Test Equipment and Instrumentation**

¹FEATURES DESCRIPTION

 Wide Bandwidth: 1000MHz The BUF602 is ^a closed-loop buffer recommended for **High Slew Rate: 8000V/**µ**^s** ^a wide range of applications. Its wide bandwidth $(1000MHz)$ and high slew rate $(8000V/\mu s)$ make it ideal for buffering very high-frequency signals. For AC-coupled applications, an optional mid-point reference (V_{REF}) is provided, reducing the number of **Output Current: 60mA (continuous)** external components required and the necessary **Peak Output Current: 350mA** supply current to provide that reference.

 Low Quiescent Current: 5.8mA The BUF602 is available in ^a standard SO-8 surface-mount package and in an SOT23-5 where ^a smaller footprint is needed.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of A Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. All trademarks are the property of their respective owners.

SBOS339B–OCTOBER 2005–REVISED MAY 2008 .. **www.ti.com**

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ORDERING INFORMATION(1)

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document or see the TI web site at www.ti.com.

ABSOLUTE MAXIMUM RATINGS(1)

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not supported.

[BUF602](http://focus.ti.com/docs/prod/folders/print/buf602.html)

ELECTRICAL CHARACTERISTICS: $V_s = \pm 5V$

Boldface limits are tested at **+25**°**C.**

At R_L = 100Ω, unless otherwise noted.

(1) Test levels: (A) 100% tested at +25°C. Over temperature limits set by characterization and simulation. (B) Limits set by characterization and simulation. (C) Typical value only for information.

(2) Junction temperature = ambient for $+25^{\circ}$ C specifications.

 (3) Junction temperature = ambient at low temperature limit; junction temperature = ambient +8°C at high temperature limit for over temperature specifications.

(4) Current is considered positive out of node.

SBOS339B–OCTOBER 2005–REVISED MAY 2008 .. **www.ti.com**

ELECTRICAL CHARACTERISTICS: $V_s = +5V$

Boldface limits are tested at **+25**°**C.**

At R_L = 100 Ω to $V_S/2$, unless otherwise noted.

(1) Test levels: (A) 100% tested at +25°C. Over temperature limits set by characterization and simulation. (B) Limits set by characterization and simulation. (C) Typical value only for information.

(2) Junction temperature = ambient for $+25^{\circ}$ C specifications.

(3) Junction temperature = ambient at low temperature limit; junction temperature = ambient +4 \degree C at high temperature limit for over temperature specifications.

(4) Current is considered positive out of node.

ELECTRICAL CHARACTERISTICS: $V_s = +5V$ **(continued)**

Boldface limits are tested at **+25**°**C.**

At R_L = 100Ω to V_S/2, unless otherwise noted.

SBOS339B–OCTOBER 2005–REVISED MAY 2008 .. **www.ti.com**

ELECTRICAL CHARACTERISTICS: $V_s = +3.3V$

Boldface limits are tested at **+25**°**C.**

At R_L = 100Ω, unless otherwise noted.

(1) Test levels: (A) 100% tested at +25°C. Over temperature limits set by characterization and simulation. (B) Limits set by characterization and simulation. (C) Typical value only for information.

(2) Junction temperature = ambient for $+25^{\circ}$ C specifications.

 (3) Junction temperature = ambient at low temperature limit; junction temperature = ambient +2°C at high temperature limit for over temperature specifications.

(4) Current is considered positive out of node.

ELECTRICAL CHARACTERISTICS: $V_s = +3.3V$ **(continued)**

Boldface limits are tested at **+25**°**C.**

At R_L = 100Ω, unless otherwise noted.

SBOS339B–OCTOBER 2005–REVISED MAY 2008 .. **www.ti.com**

TYPICAL CHARACTERISTICS: $V_s = \pm 5V$ **(continued)**

At T_A = +25°C and R_L = 100Ω, unless otherwise noted.

200 250 300

 $C_{L} = 10pF$

 $C_{L} =$ 22pF

HH

TYPICAL CHARACTERISTICS: $V_s = \pm 5V$ **(continued)**

At T_A = +25°C and R_L = 100Ω, unless otherwise noted.

www.ti.com .. SBOS339B–OCTOBER 2005–REVISED MAY 2008

TYPICAL CHARACTERISTICS: $V_s = +5V$

At T_A = +25°C and R_L = 100 Ω to V_S/2, unless otherwise noted.

[BUF602](http://focus.ti.com/docs/prod/folders/print/buf602.html)

Texas **INSTRUMENTS**

www.ti.com .. SBOS339B–OCTOBER 2005–REVISED MAY 2008

APPLICATION INFORMATION

WIDEBAND BUFFER OPERATION

The BUF602 gives the exceptional AC performance of ^a wideband buffer. Requiring only 5.8mA quiescent current, the BUF602 will swing to within 1V of either supply rail and deliver in excess of 60mA at room voltage can swing to within 1V of either supply pin temperature. This low output headroom requirement, along with supply voltage independent biasing, gives remarkable single (+5V) supply operation. The BUF602 will deliver greater than 500MHz bandwidth driving a 2V_{PP} output into 100 Ω on a single +5V supply.

Figure 31 shows the DC-coupled, dual power-supply circuit configuration used as the basis of the $±5V$ Electrical and Typical Characteristics. For test purposes, the input impedance is set to 50Ω with ^a resistor to ground and the output impedance is set to 50Ω with ^a series output resistor. Voltage swings reported in the specifications are taken directly at the input and output pins while load powers (dBm) are defined at a matched 50Ω load. In addition to the usual power-supply decoupling capacitors to ground, ^a 0.01µF capacitor can be included between the two power-supply pins. This optional added capacitor will typically improve the 2nd-harmonic distortion performance by 3dB to 6dB.

Figure 31. DC-Coupled, Bipolar Supply,

Figure 32 shows the AC-coupled, single-supply circuit configuration used as the basis of the +5V Electrical and Typical Characteristics. Though not ^a *rail-to-rail* design, the BUF602 requires minimal input and output voltage headroom compared to other very wideband buffers. It will deliver a $3V_{PP}$ output swing on ^a single +5V supply with greater than 400MHz bandwidth. The key requirement of broadband

single-supply operation of the BUF602 is to maintain output signal swings within the usable voltage ranges. The circuit of Figure 32 establishes an input midpoint bias using the internal midpoint reference. The input signal is then AC-coupled into this midpoint voltage bias. Again, on ^a single +5V supply, the output while delivering more than 60mA output current. A demanding 100Ω load to ^a midpoint bias is used in this characterization circuit.

Figure 32. AC-Coupled, Single-Supply, Specification and Test Circuit

LOW-IMPEDANCE TRANSMISSION LINES

The most important equations and technical basics of transmission lines support the results found for the various drive circuits presented here. An ideal transmission medium with zero ohmic impedance would have inductance and capacitance distributed over the transmission cable. Both inductance and capacitance detract from the transmission quality of ^a line. Each input is connected with high-impedance to the line as in ^a daisy-chain or loop-through configuration, and each adds capacitance of at least ^a few picofarads. The typical transmission line impedance (Z_0) defines the line type. In Equation 1, the impedance is calculated by the square root of line inductance (L_T) divided by line capacitance (C_T) :

$$
Z_{\rm O} = \sqrt{\frac{L_{\rm T}}{C_{\rm T}}} \tag{1}
$$

In the same manner, line inductance and capacitance The figure shown in Figure 33 makes use of the determine the delay time of a transmission line as BUF602 as a line driver. The BUF602 exhibits high shown in Equation 2: input impedance and low output impedance, making it

$$
\tau = \sqrt{L_{\tau} \times C_{\tau}}
$$
 (2)

Typical values for Z_0 are 240 Ω for symmetrical traces and 75Ω or 50Ω for coaxial cables. Z_O sometimes decreases to 30Ω to 40Ω in high data rate bus systems for bus lines on printed circuit boards (PCBs). In general, the more complex ^a bus system is, the lower Z_0 will be. Because it increases the capacitance of the transmission medium, ^a complex system lowers the typical line impedance, resulting in higher drive requirements for the line drivers used **Figure 33. Typical Line Driver Circuit** here.

Transmission lines are almost always terminated on the transmitter line and always terminated on the receiver side. Unterminated lines generate signal reflections that degrade the pulse fidelity. The driver Using the midpoint reference in conjunction with the circuit transmits the output voltage (V_{OUT}) over the BUF602 allows the creation of a low-impedance line. The signal appears at the end of the line and will reference from DC to 250MHz. be reflected when not properly terminated. The reflected portion of V_{OUT}, called V_{REFL}, returns to the driver. The transmitted signal is the sum of the original signal V_{OUT} and the reflected V_{REFL} .

$$
V_{T} = V_{OUT} + V_{REFL}
$$
 (3)

The magnitude of the reflected signal depends upon the typical line impedance (Z_O) and the value of the termination resistor Z_1 .

$$
V_{REFL} = V_{OUT} \times \Gamma
$$
 (4)

Γ denotes the reflection factor and is described by Equation 5.

$$
\Gamma = \sqrt{\frac{Z_1 - Z_0}{Z_1 + Z_0}}
$$
\n
$$
\tag{5}
$$

Γ can vary from –1 to +1.

The conditions at the corner points of Equation 5 are as follows:

An unterminated driver circuit complicates the Whenever ^a high-speed AC-coupled buffer is situation even more. V_{REFL} is reflected a second time on the driver side and wanders like ^a ping-pong ball back and forth over the line. When this happens, it is usually impossible to recover the output signal V_{OUT} dissipation. A capacitor on the output of the on the receiver side.

ideal whenever ^a buffer is required.

SELF-BIASED, LOW-IMPEDANCE MID-SUPPLY VOLTAGE REFERENCE

The 0.1µF external capacitor is used in Figure 34 to filter the noise.

Figure 34. Self-Biased, Low Impedance Mid-Supply Voltage Reference

SELF-REFERENCED, AC-COUPLED WIDEBAND BUFFER

required, you should consider the BUF602. One feature of the BUF602 is the mid-supply reference voltage, saving external components and power mid-supply reference is recommended to bandlimit the noise contribution of the mid-supply reference voltage generated by the two 50kΩ internal resistors. This circuit is shown on the front page of the datasheet.

DESIGN-IN TOOLS

DEMONSTRATION FIXTURES

Two printed circuit boards (PCBs) are available to BUF602 can drive ±3V into 25Ω or ±3.5V into 50Ω
Assist in the initial evaluation of circuit performance without exceeding the output capabilities or the 1W assist in the initial evaluation of circuit performance without exceeding variation in the BUF602 in its two package or tions. Both of dissipation limit. using the BUF602 in its two package options. Both of dissipation limit. these are offered free of charge as unpopulated PCBs, delivered with ^a user's guide. The summary information for these fixtures is shown in Table 1.

The demonstration fixtures can be requested at the Texas Instruments web site ([www.ti.com](http://www-s.ti.com/sc/techlit/http://www.ti.com)) through the BUF602 product folder.

MACROMODELS AND APPLICATIONS

Computer simulation of circuit performance using SPICE is often useful when analyzing the performance of analog circuits and systems. This is particularly true for video and RF amplifier circuits where parasitic capacitance and inductance can have ^a major effect on circuit performance. A SPICE model for the BUF602 is available through the TI web site ([www.ti.com](http://www-s.ti.com/sc/techlit/www.ti.com)). These models do ^a good job of predicting small-signal AC and transient performance under ^a wide variety of operating conditions. They do not do as well in predicting the harmonic distortion or dG/dP characteristics. These models do not attempt to distinguish between package types in their small-signal AC performance.

OUTPUT CURRENT AND VOLTAGE

The BUF602 provides output voltage and current capabilities that are not usually found in wideband buffers. Under no-load conditions at +25°C, the output voltage typically swings closer than $1.2V$ to either supply rail; the $+25^{\circ}$ C swing limit is within $1.2V$ either supply rail; the +25°C swing limit is within 1.2V Due to the high output power capability of the of either rail. Into a 15 Ω load (the minimum tested BUFE02, beatsinging or forced airflow may be load), it is tested to deliver more than ±60mA.

The specifications described above, though familiar in the industry, consider voltage and current limits separately. In many applications, it is the *voltage* \times *current*, or V-I product, which is more relevant to circuit operation. Refer to the *Buffer Output Voltage* Operating junction temperature (T_J) is given by T_A + and Current Limitations plot (Figure 16) in the Typical $P_1 \times P_2 \times P_3$. The total internal power discipation *and Current Limitations* plot [\(Figure](#page-9-0) 16) in the Typical $P_D \times \theta_{JA}$. The total internal power dissipation (P_D) is
Characteristics. The X and Y axes of this graph show the sum of quiescent power (P_{DA}) and additional the zero-voltage output current limit and the zero-current output voltage limit, respectively. The four quadrants give ^a more detailed view of the

BUF602 output drive capabilities, noting that the graph is bounded by ^a *Safe Operating Area* of 1W maximum internal power dissipation. Superimposing resistor load lines onto the plot shows that the BUF602 can drive $\pm 3V$ into 25Ω or $\pm 3.5V$ into 50Ω

The minimum specified output voltage and current over-temperature are set by worst-case simulations at the cold temperature extreme. Only at cold startup will the output current and voltage decrease to the numbers shown in the Electrical Characteristic tables. As the output transistors deliver power, the junction temperatures will increase, decreasing both V_{BE} (increasing the available output voltage swing) and increasing the current gains (increasing the available output current). In steady-state operation, the available output voltage and current will always be greater than that shown in the over-temperature specifications, since the output stage junction temperatures will be higher than the minimum specified operating ambient.

SUPPORT For a buffer, the noise model is shown in Figure 35. Equation 6 shows the general form for the output noise voltage using the terms shown in Figure 35.

Figure 35. Buffer Noise Analysis Model

$$
e_{O} = \sqrt{e_{n}^{2} + (i_{n}R_{S})^{2} + 4kTR_{S}} \quad \frac{nV}{\sqrt{Hz}}
$$
 (6)

THERMAL ANALYSIS

BUF602, heatsinking or forced airflow may be required under extreme operating conditions.
Maximum desired junction temperature will set the maximum allowed internal power dissipation as junction temperature be allowed to exceed 150°C.

the sum of quiescent power (P_{DQ}) and additional power dissipated in the output stage (P_{D1}) to deliver load power. Quiescent power is simply the specified no-load supply current times the total supply voltage

across the part. P_{DL} will depend on the required **b) Minimize the distance** (< 0.25") from the output signal and load but would, for ^a grounded power-supply pins to high-frequency 0.1µF resistive load, be at a maximum when the output is decoupling capacitors. At the device pins, the ground fixed at a voltage equal to 1/2 of either supply voltage and power-plane layout should not be in close (for equal bipolar supplies). Under this condition, P_{DL} proximity to the signal I/O pins. Avoid narrow power $=$ V_S^2

Note that it is the power in the output stage and not into the load that determines internal power dissipation.

As a worst-case example, compute the maximum ${\sf T}_{\sf J}$ supplies (for sbipolar operation) will improve using a BUF602IDBV in the circuit on the front page and-harmonic distortion performance. Larger (2.2µF
operating at the maximum specified ambient to 6.8µF) decoupling capacitors, effective at lower operating at the maximum specified ambient to 6.8µF) decoupling capacitors, effective at lower
temperature of +85°C and driving a grounded 20 Ω frequency, should also be used on the main supply temperature of +85°C and driving a grounded 20 $Ω$ load. pins. These may be placed somewhat farther from

 $P_D = 10V \times 5.8mA + 5^2/(4 \times 20\Omega) = 370.5mW$

Maximum T_J = $+85^{\circ}$ C + (0.37W × 150°C/W) = 141°C.

junction temperature, system reliability considerations **performance of the BUF602.** Resistors should be ^a may require lower tested junction temperatures. The very low reactance type. Surface-mount resistors
highest possible internal dissipation will occur if the vork best and allow a tighter overall layout. Metal film highest possible internal dissipation will occur if the work best and allow a tighter overall layout. Metal film
load requires current to be forced into the output for or carbon composition, axially-leaded resistors can load requires current to be forced into the output for or carbon composition, axially-leaded resistors can
positive output voltages or sourced from the output also provide good high-frequency performance. positive output voltages or sourced from the output also provide good high-frequency performance. for negative output voltages. This puts a high current Again, keep their leads and PCB traces as short as the the strates of the output as the possible. Never use wirewound type resistors in a through a large internal voltage drop in the output transistors. The output V-I plot ([Figure](#page-9-0) 16) shown in the Typical Characteristics include ^a boundary for 1W **d) Connections to other wideband devices** on the maximum internal power dissipation under these conditions.

BOARD LAYOUT GUIDELINES

performance high-frequency amplifier like the BUF602 requires careful attention to board layout parasitics and around them. If a long trace is required, and the 6dB
external component types. Becommendations that signal loss intrinsic to a doubly-terminated external component types. Recommendations that will optimize performance include:

a) Minimize parasitic capacitance to any AC ground stripline techniques (consult an ECL design handbook for all of the signal I/O pins. Parasitic capacitance on for microstrip and stripline lavout techniques). A 500 for all of the signal I/O pins. Parasitic capacitance on for microstrip and stripline layout techniques). A 50Ω
The output pins can cause instability: on the environment is normally not necessary on board and the output pins can cause instability: on the environment is normally not necessary on board, and
the sourinverting input, it can react with the source in fact, a higher impedance environment will improve noninverting input, it can react with the source in fact, a higher impedance environment will improve
impedance to cause unintentional bandlimiting. To distortion as shown in the distortion versus load plots reduce unwanted capacitance, ^a window around the signal I/O pins should be opened in all of the ground and power planes around those pins. Otherwise, ground and power planes should be unbroken elsewhere on the board.

and ground traces to minimize inductance between the pins and the decoupling capacitors. The power-supply connections should always be decoupled with these capacitors. An optional supply decoupling capacitor (0.1µF) across the two power the device and may be shared among several devices in the same area of the PCB.

c) Careful selection and placement of external Although this is still below the specified maximum **components will preserve the high-frequency** high-frequency application.

board may be made with short, direct traces or through onboard transmission lines. For short connections, consider the trace and the input to the next device as ^a lumped capacitive load. Relatively Achieving optimum performance with a wide-traces (50mils to 100mils) should be used, preferably with ground and power planes opened up intrinsic to a doubly-terminated transmission line is acceptable, implement ^a matched impedance transmission line using microstrip or distortion as shown in the distortion versus load plots.

> **e) Socketing ^a high-speed part like the BUF602 is not recommended.** The additional lead length and pin-to-pin capacitance introduced by the socket can create an extremely troublesome parasitic network that makes it almost impossible to achieve ^a smooth, stable frequency response. Best results are obtained by soldering the BUF602 onto the board.

INPUT AND ESD PROTECTION

The BUF602 is built using ^a very high-speed complementary bipolar process. The internal junction breakdown voltages are relatively low for these very small geometry devices. These breakdowns are reflected in the *Absolute Maximum Ratings* table. All device pins are protected with internal ESD protection diodes to the power supplies as shown in Figure 36.

Figure 36. Internal ESD Protection

www.ti.com .. SBOS339B–OCTOBER 2005–REVISED MAY 2008

These diodes provide moderate protection to input overdrive voltages above the supplies as well. The protection diodes can typically support 30mA continuous current. Where higher currents are possible (for example, in systems with ±15V supply parts driving into the BUF602), current-limiting series resistors should be added into the two inputs. Keep these resistor values as low as possible since high values degrade both noise performance and frequency response.

Revision History

PACKAGING INFORMATION

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the \leq =1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

TEXAS NSTRUMENTS

www.ti.com 5-Jan-2022

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

www.ti.com 5-Jan-2022

PACKAGE MATERIALS INFORMATION

*All dimensions are nominal

www.ti.com 5-Jan-2022

TUBE

*All dimensions are nominal

PACKAGE OUTLINE

DBV0005A SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR

NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. Refernce JEDEC MO-178.
- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.

EXAMPLE BOARD LAYOUT

DBV0005A SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.

PACKAGE OUTLINE

D0008A SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](https://www.ti.com/legal/terms-conditions/terms-of-sale.html) or other applicable terms available either on [ti.com](https://www.ti.com) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2023, Texas Instruments Incorporated